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ON Semiconductor® FDBL9406-F085

N-Channel PowerTrench[®] MOSFET

40 V, 240 A, 1.2 mΩ

Features

- Typical $R_{DS(on)}$ = 0.9 m Ω at V_{GS} = 10V, I_D = 80 A
- Typical Q_{g(tot)} = 90 nC at V_{GS} = 10V, I_D = 80 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12V Systems



MOSFET Maximum Ratings T_J = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		40	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	240		
I _D	Pulsed Drain Current	T _C = 25°C	See Figure 4	— A	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	316	mJ	
D	Power Dissipation		300	W	
P _D	Derate Above 25°C		2.0	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.5	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W	

Notes:

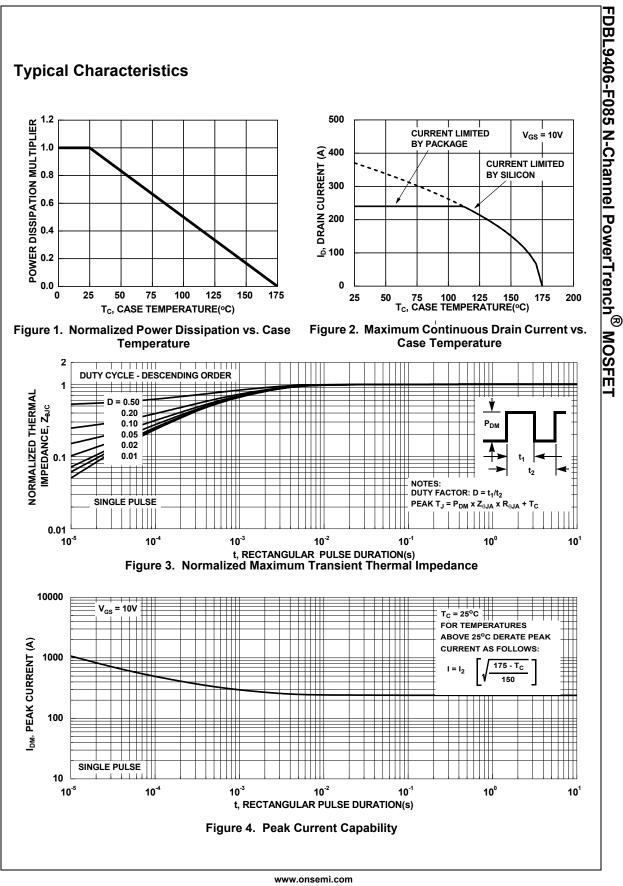
1: Current is limited by bondwire configuration.

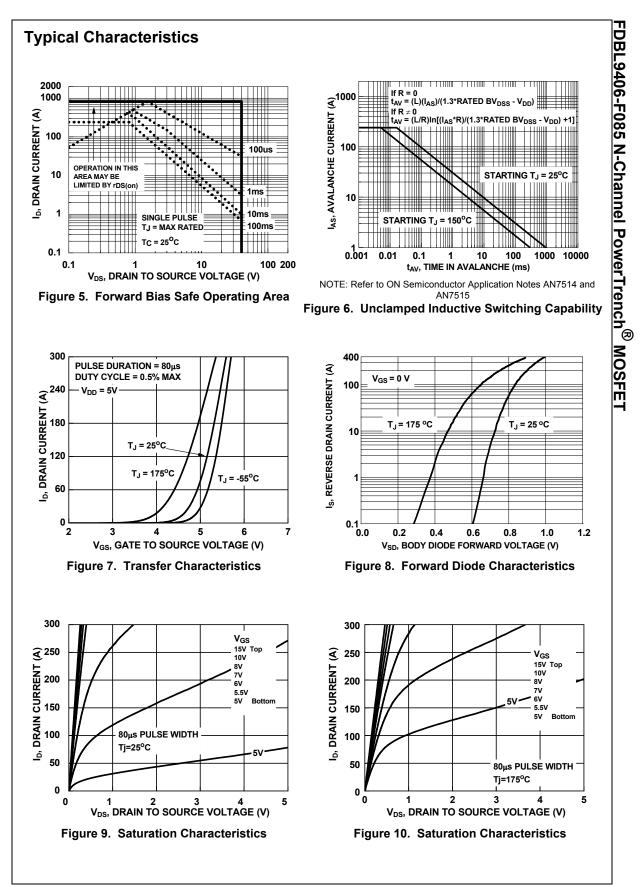
2: Starting T_J = 25°C, L = 0.1mH, I_{AS} = 79.5A, V_{DD} = 40V during inductor charging and V_{DD} = 0V during time in avalanche. 3: $R_{0,JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder moduling surface of the drain pins. $R_{\theta JC}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

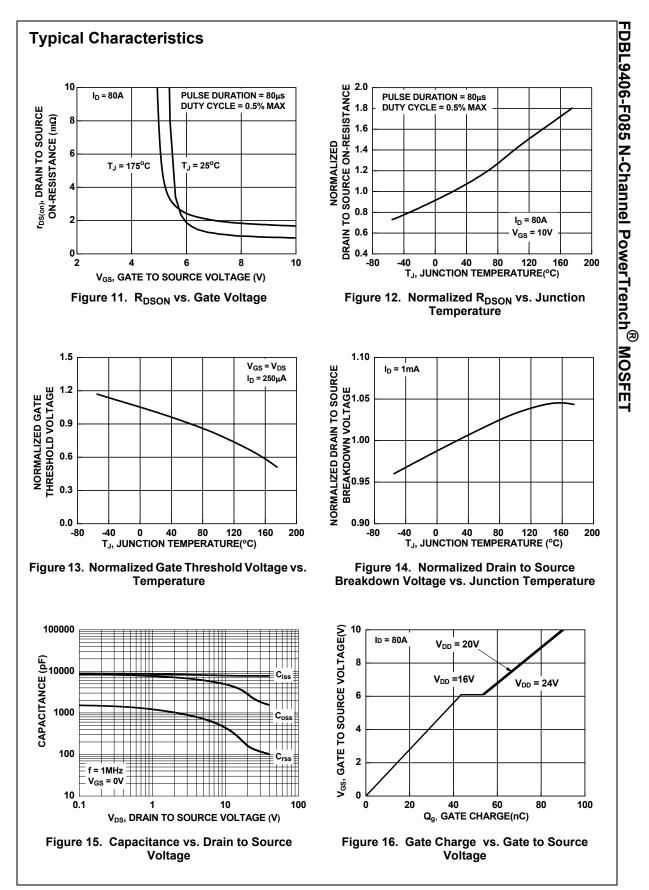
Device Marking	Device	Package			
FDBL9406	FDBL9406-F085	MO-299A	-	-	-

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	aracteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		40	-	-	V
		V_{DS} =40V, T_J = 25°C		-	-	1	μA
IDSS	Drain-to-Source Leakage Current	$V_{GS} = 0V$	T _J = 175 ^o C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA		2.0	3.2	4.0	V
		I _D = 80A,	T _{.1} = 25 ^o C	-	0.90	1.20	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V	$T_{\rm J} = 175^{\rm o} {\rm C} \ ({\rm Note} \ 4)$	-	1.64	1.86	mΩ
-	ic Characteristics				1		
C _{iss}	Input Capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		-	7735	-	pF
C _{oss}	Output Capacitance			-	2160	-	pF
C _{rss}	Reverse Transfer Capacitance			-	129	-	pF
R _g	Gate Resistance	f = 1MHz		-	2.5	-	Ω
Q _{g(ToT)}	Total Gate Charge at 10V	V _{GS} = 0 to 1		-	90	107	nC
Q _{g(th)}	Threshold Gate Charge	V _{GS} = 0 to 2	V I _D = 80A	-	13.5	15.5	nC
Q _{gs}	Gate-to-Source Gate Charge	-		-	43	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge			-	10	-	nC
Switchi	ng Characteristics						
t _{on}	Turn-On Time			-	-	102	ns
t _{d(on)}	Turn-On Delay		-	-	33	-	ns
t _r	Rise Time	$V_{DD} = 20V, I_D = 80A,$ $V_{GS} = 10V, R_{GEN} = 6\Omega$		-	40	-	ns
t _{d(off)}	Turn-Off Delay			-	47	-	ns
t _f	Fall Time			-	23	-	ns
t _{off}	Turn-Off Time			-	-	91	ns
Drain-S	ource Diode Characteristics						
V.	Source to Drain Diade Voltage	I _{SD} =80A, V _{GS} = 0V		-	-	1.25	V
V _{SD}	Source-to-Drain Diode Voltage	I _{SD} = 40A, V _{GS} = 0V		-	-	1.2	V
	Reverse-Recovery Time	I _F = 80A, dI _{SD} /dt = 100A/μs, V _{DD} =32V		-	91	107	ns
t _{rr}					128	167	nC





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